

## INT-A-PAK Power Module Thyristor/Diode, 300 A



INT-A-PAK

| PRIMARY CHARACTERISTICS |                              |  |  |  |
|-------------------------|------------------------------|--|--|--|
| I <sub>T(AV)</sub>      | 300 A                        |  |  |  |
| Туре                    | Modules -thyristor, standard |  |  |  |
| Package                 | INT-A-PAK                    |  |  |  |

#### **FEATURES**

- · Electrically isolated base plate
- 3000 V<sub>RMS</sub> isolating voltage



- · Industrial standard package
- Simplified mechanical designs, rapid assembly
- · High surge capability
- Large creepage distances
- UL approved file E78996 **T**
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **APPLICATIONS**

- · Battery chargers
- Welders
- Power converters
- Alternators

| MAJOR RATINGS AND CHARACTERISTICS  |                 |             |                   |  |  |  |
|------------------------------------|-----------------|-------------|-------------------|--|--|--|
| SYMBOL                             | CHARACTERISTICS | VALUES      | UNITS             |  |  |  |
| V <sub>DRM</sub> /V <sub>RRM</sub> |                 | 800         | V                 |  |  |  |
| I <sub>T(AV)</sub>                 | 53 °C           | 300         | Α                 |  |  |  |
| I <sub>T(RMS)</sub>                |                 | 116         | Α                 |  |  |  |
| ,                                  | 50 Hz           | 6500        | ٨                 |  |  |  |
| ITSM                               | 60 Hz           | 6900        | А                 |  |  |  |
| 2t                                 | 50 Hz           | 214         | kA <sup>2</sup> s |  |  |  |
| 1-1                                | 60 Hz           | 195         | KA-S              |  |  |  |
| I <sup>2</sup> √t                  |                 | 2140        | kA²√s             |  |  |  |
| TJ                                 | Range           | -40 to +140 | °C                |  |  |  |

### **ELECTRICAL SPECIFICATIONS**

| VOLTAGE RATINGS  |  |  |   |  |  |  |  |
|------------------|--|--|---|--|--|--|--|
| TYPE NUMBER      | V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | V <sub>RSM</sub> /V <sub>DSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub> /I <sub>DRM</sub><br>AT 125 °C<br>mA |  |  |  |  |
| VS-VSKL300/08PbF | 800  | 900  | 50  |  |  |  |  |



| ON-STATE CONDUCTION                              |                     |   |                                    |  |        |                     |  |
|--|---------------------|---|------------------------------------|--|--------|---------------------|--|
| PARAMETER  | SYMBOL              | TEST CONDITIONS   |                                    |  | VALUES | UNITS               |  |
| Maximum average on-state current                 | <b>I</b>            | 180° conduction   | 180° conduction half sine wave     |  |        | А                   |  |
| at case temperature                              | I <sub>T(AV)</sub>  | 100 Conduction  | irrian sine wave                   |  | 53     | °C                  |  |
| Maximum RMS on-state current                     | I <sub>T(RMS)</sub> | As AC switch  |                                    |  | 116    |                     |  |
|  |                     | t = 10 ms   | No voltage                         |  | 6600   |                     |  |
| Maximum peak, one-cycle on-state, non-repetitive |                     | t = 8.3 ms  | reapplied                          |  | 6900   | Α                   |  |
| surge current                                    | I <sub>TSM</sub>    | t = 10 ms   | 100 % V <sub>RBM</sub>             |  | 5500   |                     |  |
| · ·  |                     | t = 8.3 ms  | reapplied                          | Sine half wave,                                    |        | 5800                |  |
|  |                     | t = 10 ms   | No voltage                         | initial T <sub>J</sub> =<br>T <sub>J</sub> maximum | 214    | - kA <sup>2</sup> s |  |
| Maximum I <sup>2</sup> t for fusing              | l <sup>2</sup> t    | t = 8.3 ms  | reapplied                          |  | 195    |                     |  |
|  | 1-1                 | t = 10 ms   | 100 % V <sub>RBM</sub>             |  | 151    |                     |  |
|  |                     | t = 8.3 ms  | reapplied                          |  | 138    |                     |  |
| Maximum I²√t for fusing                          | I <sup>2</sup> √t   | t = 0.1 ms to 10  | ms, no voltage rea                 | applied  | 2140   | kA²√s               |  |
| Low level value of threshold voltage             | V <sub>T(TO)1</sub> | (16.7 % x π x I <sub>T</sub>  | $(AV) < I < \pi \times I_{T(AV)},$ | T <sub>J</sub> maximum                             | 0.796  | V                   |  |
| High level value of threshold voltage            | V <sub>T(TO)2</sub> | $(I > \pi \times I_{T(AV)}), T_{Q}$   | <sub>J</sub> maximum               |  | 0.868  | V                   |  |
| Low level value on-state slope resistance        | r <sub>t1</sub>     | $(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}), T_{J} \text{ maximum}$ |                                    |  | 0.972  | mΩ                  |  |
| High level value on-state slope resistance       | r <sub>t2</sub>     | (I > $\pi$ x I <sub>T(AV)</sub> ), T <sub>J</sub> maximum                                 |                                    |  | 0.88   | 1117.7              |  |
| Maximum on-state voltage drop                    | $V_{TM}$            | T 25 °C 1   | - 500 A                            | SCR  | 1.35   | V                   |  |
| iviaximum on-state voltage drop                  | $V_{FM}$            | $T_J = 25  ^{\circ}\text{C}, I_{pk} =$  | - 300 A                            | DIODE  | 1.20   | V                   |  |

| SWITCHING             |                |  |        |       |
|-----------------------|----------------|--|--------|-------|
| PARAMETER             | SYMBOL         | TEST CONDITIONS  | VALUES | UNITS |
| Typical delay time    | t <sub>d</sub> | Gate current 1 A, $dl_g/dt = 1 A/\mu s$<br>$V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$   | 1.0    |       |
| Typical turn-off time | t <sub>q</sub> | $I_{TM}$ = 300 A, $T_J$ = $T_J$ maximum, dl/dt = 20 A/μs, $V_R$ = 50 V dV/dt = 20 V/μs, Gate 0 V 100 $\Omega$ , $t_p$ = 500 μs | 100    | μs    |

| BLOCKING   |  |   |        |       |
|--|--|---|--------|-------|
| PARAMETER  | SYMBOL                                 | TEST CONDITIONS                                       | VALUES | UNITS |
| Maximum critical rate of rise of off-state voltage | dV/dt                                  | $T_J = T_J$ maximum linear to 67 % rated $V_{DRM}$    | 500    | V/µs  |
| Maximum peak reverse and off-state leakage current | I <sub>DRM</sub> ,<br>I <sub>RRM</sub> | $T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied  | 50     | mA    |
| RMS insulation voltage                             | V <sub>INS</sub>                       | 50 Hz, circuit to base, all terminal shorted, t = 1 s | 3000   | V     |



| TRIGGERING   |                    |   |        |       |  |
|--|--------------------|---|--------|-------|--|
| PARAMETER  | SYMBOL             | TEST CONDITIONS   | VALUES | UNITS |  |
| Maximum peak gate power                                  | P <sub>GM</sub>    | $T_J = T_J$ maximum, $t_p \le 5$ ms   | 10.0   | W     |  |
| Maximum average gate power                               | P <sub>G(AV)</sub> | $T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$  | 2.0    | VV    |  |
| Maximum peak positive gate current                       | I <sub>GM</sub>    | $T_J = T_J$ maximum, $t_p \le 5$ ms   | 3.0    | Α     |  |
| Maximum required DC gate voltage to trigger              | $V_{GT}$           |   | 3      | V     |  |
| Maximum required DC gate current to trigger              | I <sub>GT</sub>    | $T_J = 25 ^{\circ}\text{C}$<br>Anode supply: 12 V resistive load  | 200    | mA    |  |
| Maximum holding current                                  | I <sub>H</sub>     | Allode Supply. 12 V Toolstive load  | 600    | ША    |  |
| Maximum peak positive gate voltage                       | +V <sub>GM</sub>   | T <sub>.l</sub> = T <sub>.l</sub> maximum, t <sub>n</sub> ≤ 5 ms  | 20     | V     |  |
| Maximum peak negative gate voltage                       | -V <sub>GM</sub>   | $t_{J} = t_{J} \text{ maximum, } t_{p} \leq 5 \text{ ms}$   | 5.0    | V     |  |
| DC gate voltage not to trigger                           | $V_{GD}$           | $T_J = T_J$ maximum   | 0.30   | V     |  |
| DC gate current not to trigger                           | I <sub>GD</sub>    | Maximum gate current/voltage not to trigger is<br>the maximum value which will not trigger any<br>unit with rated V <sub>DRM</sub> anode to cathode applied | 10     | mA    |  |
| Maximum non-repetitive rate of rise of turned-on current | dI/dt              | Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$   | 1000   | A/µs  |  |

| THERMAL AND MECHANICAL SPECIFICATIONS                     |                   |   |             |       |  |  |  |
|---|-------------------|---|-------------|-------|--|--|--|
| PARAMETER   | SYMBOL            | TEST CONDITIONS                               | VALUES      | UNITS |  |  |  |
| Maximum junction operating temperature range              | TJ                |   | -40 to +140 | °C    |  |  |  |
| Maximum storage temperature range                         | T <sub>Stg</sub>  |   | -40 to +150 |       |  |  |  |
| Maximum thermal resistance, junction to case per junction | R <sub>thJC</sub> | DC operation                                  | 0.19        | K/W   |  |  |  |
| Maximum thermal resistance, case to heatsink per module   | R <sub>thCS</sub> | Mounting surface smooth, flat and greased     | 0.035       | N/VV  |  |  |  |
| Mounting torque + 10 %                                    | k                 | A mounting compound is recommended and 4 to 6 | 4 to 6      | Nima  |  |  |  |
| Mounting torque ± 10 % busbar to IAF                      | •                 | the torque should be rechecked after a period | 4 10 6      | Nm    |  |  |  |
| Approximate weight  |                   | of 3 hours to allow for the spread of the     | 500         | g     |  |  |  |
| Approximate weight  |                   | compound. Lubricated threads.                 | 17.8        | OZ.   |  |  |  |
| Case style  |                   |   | INT-A-F     | AK    |  |  |  |

| AR CONDUCTION PER JUNCTION |       |  |       |       |       |       |       |       |       |       |     |
|----------------------------|-------|--|-------|-------|-------|-------|-------|-------|-------|-------|-----|
| DEVICES                    | •     | SINUSOIDAL CONDUCTION<br>AT T <sub>J</sub> MAXIMUM |       |       |       |       |       |       |       | UNITS |     |
|                            | 180°  | 120°   | 90°   | 60°   | 30°   | 180°  | 120°  | 90°   | 60°   | 30°   |     |
| VSKL300                    | 0.019 | 0.022  | 0.028 | 0.041 | 0.068 | 0.013 | 0.023 | 0.031 | 0.043 | 0.069 | K/W |

### Note

Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

### www.vishay.com

## Vishay Semiconductors

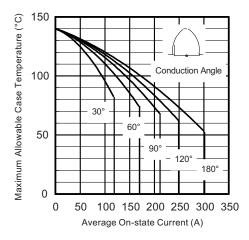


Fig. 1 - Current Ratings Characteristics

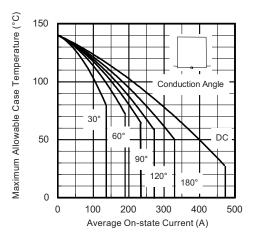


Fig. 2 - Current Ratings Characteristics

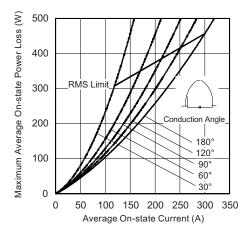


Fig. 3 - On-State Power Loss Characteristics

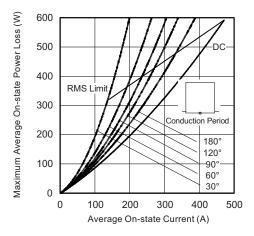


Fig. 4 - On-State Power Loss Characteristics

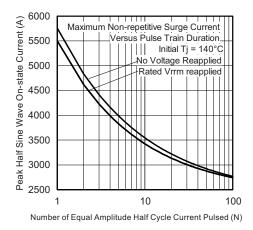


Fig. 5 - Maximum Non-Repetitive Surge Current

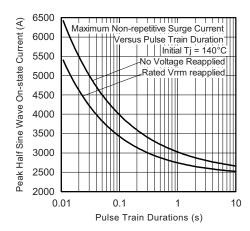
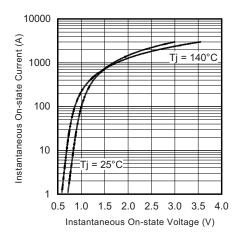


Fig. 6 - Maximum Non-Repetitive Surge Current





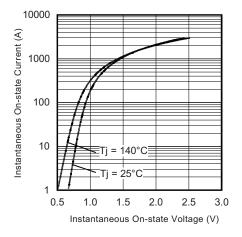


Fig. 8 - On-State Voltage Drop Characteristics (Diode)

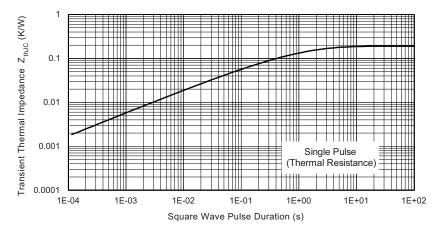
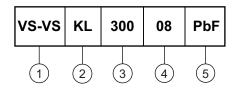


Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

2 - Circuit configuration

Current rating (300 = 300 A)

Voltage rating (08 = 800 V)

5 - PbF = Lead (Pb)-free



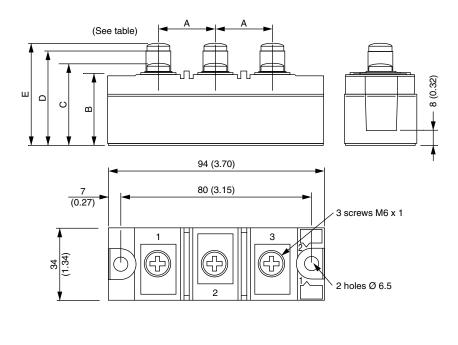
| CIRCUIT CONFIGURATION                       |                               |  |  |  |  |  |
|---|-------------------------------|--|--|--|--|--|
| CIRCUIT DESCRIPTION                         | CIRCUIT<br>CONFIGURATION CODE | CIRCUIT DRAWING  |  |  |  |  |
| SCR/diode doubler circuit, negative control | L                             | 10~<br>20+<br>10~<br>20+<br>10~<br>10~<br>10~<br>10~<br>10~<br>10~<br>10~<br>10~ |  |  |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |
|----------------------------|--------------------------|--|--|--|
| Dimensions                 | www.vishay.com/doc?95010 |  |  |  |



## **INT-A-PAK Diode**

### **DIMENSIONS** in millimeters (inches)



| Α         | В         | С         | D | E |
|-----------|-----------|-----------|---|---|
| 23 (0.91) | 30 (1.18) | 36 (1.42) | - | - |



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